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# Ultrafast terahertz-field-driven ionic response in ferroelectric BaTiO<sub>3</sub>

F. Chen,<sup>1,2</sup> Y. Zhu,<sup>3</sup> S. Liu,<sup>4,5</sup> Y. Qi,<sup>4</sup> H. Y. Hwang,<sup>6</sup> N. C. Brandt,<sup>6</sup> J. Lu,<sup>6</sup> F. Quirin,<sup>7</sup> H. Enquist,<sup>8</sup> P. Zalden,<sup>2</sup> T. Hu,<sup>9</sup>

J. Goodfellow,<sup>9</sup> M.-J. Sher,<sup>9,2</sup> M. C. Hoffmann,<sup>10</sup> D. Zhu,<sup>10</sup> H. Lemke,<sup>10</sup> J. Glownia,<sup>10</sup> M. Chollet,<sup>10</sup> A. R. Damodaran,<sup>11</sup>

J. Park,<sup>12</sup> Z. Cai,<sup>3</sup> I. W. Jung,<sup>13</sup> M. J. Highland,<sup>14</sup> D. A. Walko,<sup>3</sup> J. W. Freeland,<sup>3</sup> P. G. Evans,<sup>12</sup> A. Vailionis,<sup>15</sup> J. Larsson,<sup>16</sup>

K. A. Nelson,<sup>6</sup> A. M. Rappe,<sup>4</sup> K. Sokolowski-Tinten,<sup>7</sup> L. W. Martin,<sup>11,17</sup> H. Wen,<sup>3,\*</sup> and A. M. Lindenberg<sup>2,9,18,†</sup>

<sup>1</sup>Department of Electrical Engineering, Stanford University, Stanford, California 94305, USA

<sup>2</sup>SIMES Institute for Materials and Energy Sciences, SLAC National Accelerator Laboratory, Menlo Park, California 94025, USA

<sup>3</sup>Advanced Photon Source, Argonne National Laboratory, Argonne, Illinois 60439, USA

<sup>4</sup>The Makineni Theoretical Laboratories, Department of Chemistry, University of Pennsylvania,

Philadelphia, Pennsylvania 19104-6323, USA

<sup>5</sup>Geophysical Lab, Carnegie Institute for Science, Washington, DC 20015, USA

<sup>6</sup>Department of Chemistry, Massachusetts Institute of Technology, Cambridge, Massachusetts 02139, USA

<sup>7</sup> Faculty of Physics and Center for Nanointegration Duisburg-Essen (CENIDE), University of Duisburg-Essen,

Lotharstrasse 1, 47048 Duisburg, Germany

<sup>8</sup>MAX IV Laboratory, Lund University, S-22100 Lund, Sweden

<sup>9</sup>Department of Materials Science and Engineering, Stanford University, Stanford, California 94305, USA

<sup>10</sup>Linac Coherent Light Source, SLAC National Accelerator Laboratory, Menlo Park, California 94025, USA

<sup>11</sup>Department of Materials Science and Engineering, University of California Berkeley, Berkeley, California 94720, USA

<sup>12</sup>Department of Materials Science and Engineering, University of Wisconsin, Madison, Madison, Wisconsin 53706, USA

<sup>13</sup>Center for Nanoscale Materials, Argonne National Laboratory, Argonne, Illinois 60439, USA

<sup>14</sup>Materials Science Division, Argonne National Laboratory, Argonne, Illinois 60439, USA

<sup>15</sup>Geballe Laboratory for Advanced Materials, Stanford University, Stanford, California 94305, USA <sup>16</sup>Department of Physics, Lund University, S-22100 Lund, Sweden

<sup>17</sup>Materials Science Division, Lawrence Berkeley National Laboratory, Berkeley, California 94720, USA <sup>18</sup>PULSE Institute, SLAC National Accelerator Laboratory, Menlo Park, California 94025, USA (Received 27 January 2016; revised manuscript received 24 October 2016; published 22 November 2016)

The dynamical processes associated with electric field manipulation of the polarization in a ferroelectric remain largely unknown but fundamentally determine the speed and functionality of ferroelectric materials and devices. Here we apply subpicosecond duration, single-cycle terahertz pulses as an ultrafast electric field bias to prototypical BaTiO<sub>3</sub> ferroelectric thin films with the atomic-scale response probed by femtosecond x-ray-scattering techniques. We show that electric fields applied perpendicular to the ferroelectric polarization drive large-amplitude displacements of the titanium atoms along the ferroelectric polarization axis, comparable to that of the built-in displacements associated with the intrinsic polarization and incoherent across unit cells. This effect is associated with a dynamic rotation of the ferroelectric polarization switching on and then off on picosecond time scales. These transient polarization modulations are followed by long-lived vibrational heating effects driven by resonant excitation of the ferroelectric soft mode, as reflected in changes in the c-axis tetragonality. The ultrafast structural characterization described here enables a direct comparison with first-principles-based molecular-dynamics simulations, with good agreement obtained.

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Ferroelectric materials are comprised of noncentrosymmetric unit cells with permanent electric dipole moments switchable by electric fields, and they exhibit strong coupling between polarization, strain, and electronic degrees of freedom. Strong light-matter coupling and photoferroelectric responses associated with these materials have enabled nextgeneration photovoltaic applications as well as novel optical detection technology spanning the range from visible to farinfrared frequencies [1-5]. In recent years, new possibilities to manipulate the functional properties of ferroelectrics with light have emerged, holding promise both for directing these coupled degrees of freedom and for elucidating their fundamental dynamical properties [6-13]. In particular, at

the heart of ferroelectric-based next-generation piezoelectric, electrocaloric, electro-optic, and nonvolatile memory devices and sensors lies the dynamics of electric polarization [14–18]. Although studies of electric-field-driven polarization dynamics have been carried out in the past through the application of short electrical pulses, these are complicated by difficulties coupling electrical pulses through electrode structures on sub-100-picosecond (ps) time scales, whereas the intrinsic atomic-scale response is orders of magnitude faster. Prior studies [15,19] have shown evidence for subnanosecond time-scale dynamics in response to electrical bias fields. Optical [7,20,21] and x-ray studies [6,9,22,23] have captured information about the dynamics of ferroelectrics upon optical excitation, whereas the intrinsic atomic-scale response to applied electric fields is largely unexplored. Whereas it was possible for prior theoretical work to focus on the influence of electric-field-driven dynamics in ferroelectrics on short time scales [14,17,24],

<sup>\*</sup>wen@aps.anl.gov

<sup>&</sup>lt;sup>†</sup>aaronl@stanford.edu



FIG. 1. Experimental setup, applied THz field, and enhancement electrode structure. (a) Sample schematic showing ferroelectric polarization perpendicular to the film along [001]. The field is applied with light polarization orthogonal to the ferroelectric polarization. The inset shows the pseudocubic unit cell of BTO. (b) Applied THz electric field as a function of time, measured by electro-optic sampling at the sample position at LCLS.

direct comparisons between molecular-dynamics (MD) simulations and the actual atomic-scale response have not been previously carried out. Here we use single-cycle, sub-ps duration terahertz (THz) pulses as an all-optical means to apply an electric field bias to the prototypical ferroelectric BaTiO<sub>3</sub> (BTO), while resolving the time-dependent atomicscale response *in situ* using femtosecond x-ray-scattering techniques. In particular, we obtain a direct view of the atomic displacements within the unit cell upon THz excitation, resonant with the soft mode of BTO. Experimental measurements are compared with state-of-the-art MD simulations, providing a microscopic picture of the atomic-scale response to ultrafast electric field stimulation on ps time scales.

THz pump/x-ray probe measurements with ≈200 femtosecond temporal resolution were carried out at the Linac Coherent Light Source (LCLS) at the SLAC National Accelerator Laboratory probing the time-dependent structural response of 90 nm single domain BTO thin films deposited on NdScO<sub>3</sub> substrates, with ferroelectric polarization pointing normal to the surface (see Fig. 1). Additional measurements on the same sample were carried out at the Advanced Photon Source at Argonne National Laboratory using microfocused 100 ps x-ray pulses [25] to probe the response at higher fields within split-ring resonator structures (see the Supplemental Material [26] for further details on the experimental setup). Motivated in part by recent theoretical studies [24], the THz field was applied in-plane and perpendicular to the ferroelectric polarization. Transient THz-induced responses were measured for specific points on the (003) BTO x-ray rocking curve corresponding to the maximum, and half intensity at lower and higher angles of the diffraction peak [Figs. 2(a)-2(d)]. At the peak of the rocking curve [Fig. 2(b)] where one is insensitive to rocking curve shifts, we observe a fast transient increase in the diffracted intensity of approximately 1%, seen also in the measurements on the lower-angle and higher-angle sides near time-zero [Figs. 2(c) and 2(d)]. This short time increase is associated with an x-ray structure factor increase occurring on a time scale comparable to the THz pulse duration and lasting of order 10 ps, discussed further below. Following the transient increase observed at all points on the rocking curve in the first 10 ps, we observe a time-dependent increase (decrease) in



FIG. 2. Terahertz-pump x-ray probe measurements and field dependence. (a) Static BTO (003) rocking curve at room temperature, with three specific incident angles marked as 1, 2, and 3 corresponding to the angles where the time scans (b), (c), and (d) were measured. Red curves are simulations using dynamical diffraction theory based on calculated THz-driven strains and structure factor modulations. (e) The differential rocking curve at t = 5 and 15 ps comparing the rocking curves measured with and without THz excitation. (f) Dependence of change in diffracted intensity on the THz peak field, measured at t = 15 ps on the high-angle side of the rocking curve. The red curve is the quadratic fit.

scattering intensity on the lower angle (higher angle) sides, associated with the development of a long-lived shift of the diffraction peak to lower angles with an onset time of  $\approx 15$  ps. This is consistent with a homogeneous stress induced by the THz field where the observed time scale is determined by the sample thickness divided by the longitudinal sound velocity (90 nm/6000 m/s = 15 ps) [27].

The observed changes in the diffracted intensity are consistent with rocking curve scans (measured by integrating over the entire diffracted intensity on an area detector) taken at different relative time delays between the THz and x-ray pulses. At t = 5 ps, the differential rocking curve [Fig. 2(e)] shows an overall increase at all angles probed. At t = 15 ps, a clear shift of the rocking curve to lower angle emerges, with magnitude scaling quadratically with the applied field



FIG. 3. Terahertz-pump x-ray probe measurements within splitring resonator structure. (a) (002) rocking curve before (t = -900 ps) and after (t = 100 ps) time zero showing large-amplitude fieldinduced tensile strain. (b) Nanosecond time-dependent intensity measured at the low-angle side of the rocking curve below and above the Curie temperature. Also shown (solid line) are fits to a thermal model for the cooling of the BTO film in the paraelectric phase into the substrate, described in the Supplemental Material.

[Fig. 2(f)]. Measurements at higher fields within split-ring resonator structures using microfocused x-ray probes, shown in Figs. 3(a) and 3(b), show larger effects, with peak shifts corresponding to terahertz-driven tensile strains of 0.04% in the out-of-plane direction. Based on static temperaturedependent x-ray-diffraction measurements, we estimate that the observed shift toward lower angle corresponds to a fieldinduced heating of 72 K (see the Supplemental Material [26]). The shift in rocking curve is a long-lived effect showing a 10 ns recovery [Fig. 3(b)]. This long recovery time constant is consistent with simulations of thermal transport assuming rough values for the interfacial thermal conductivity (see the Supplemental Material [26]). Slight asymmetric changes of the rocking curve may be related to inhomogeneity in the strain within the film. Similar expansions in the *c*-axis lattice spacing are observed comparing THz-driven effects at room temperature to those observed above the Curie temperature [Fig. 3(b)].

We interpret the observed short- and long-time effects as a result of direct THz-driven coupling to the lattice, initially driving polar displacements along the direction of the applied electric field (within the plane of the sample). Because measurements of the (003) diffraction peak provide sensitivity only to the out-of-plane atomic displacements, the structure factor modulation observed at short times can therefore be understood as arising from the coupling of initially excited in-plane atomic displacements within the unit cell to out-of-plane displacements, as has been predicted to occur in prior theoretical work [24] and the MD simulation as discussed later. In particular, we show in the following that the observed increase in scattering intensity at short times is indicative of a transient increase in the out-of-plane rms displacements of the central Ti atoms, associated with an ultrafast rotation of the macroscopic ferroelectric polarization.

The structure factor for the probed (003) reflection can be written simply as

$$\sum_{n} f_{n} e^{2\pi i (hx_{n} + ky_{n} + lz_{n})}|_{h=0,k=0,l=3} = f_{\text{Ba}} - f_{\text{Ti}} e^{-6\pi i \delta}, \quad (1)$$

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where  $f_{Ba}$  and  $f_{Ti}$  are the scattering factors for the Ba and Ti atoms in the unit cell, (hkl) are the Miller indices for the probed reflection,  $(x_n, y_n, z_n)$  are the fractional coordinates of the Ti atom, and  $\delta$  is the out-of-plane fractional displacement of the Ti atom measured from the center of the unit cell. Here we neglect the contribution from the oxygen atoms. For small  $\delta$ , the scattered waves from the Ba and Ti atoms scatter  $\pi$  out of phase with each other and destructively interfere, with the nonzero intensity of the reflection arising from the different scattering factors for the Ba and Ti atoms. Time-dependent displacements of the atoms will modulate this destructive interference and qualitatively explain the observed time-dependent increase in scattering efficiency. In a simple harmonic-oscillator model, if the THz pulse induces a time-dependent out-of-plane vibrational excitation of the Ti atom with amplitude A [23], the time-dependent structure factor becomes

$$F_{003}(t) = f_{\text{Ba}} - f_{\text{Ti}} \exp\{-6\pi i [\delta + A(t)]\}.$$
 (2)

Since no coherent oscillatory response is observed when spatially averaging over all unit cells, we consider the impact of a finite time-dependent rms displacement  $\sqrt{\langle A(t)^2 \rangle} = A_{\rm rms}(t)$ . One may then show quantitatively from Eq. (1) (see also Sec. 3 in the Supplemental Material [26]) that this leads to a fractional increase in the (003) scattered intensity given by

$$\frac{\Delta I}{I_o} \sim \frac{36 f_{\rm Ba} f_{\rm Ti} \pi^2 A_{\rm rms}^2(t)}{(f_{\rm Ba} - f_{\rm Ti})^2}.$$
(3)

For a 1% increase of the diffraction intensity as experimentally observed, Eq. (3) gives a peak rms displacement amplitude  $A_{\rm rms} = 0.03$  Å, corresponding to an out-of-plane modulation comparable to the built-in ferroelectric displacement [28]. We compare the observed response to MD simulations (see Fig. 4 and the Supplemental Material), which predict peak rms displacements of the central Ti atom of 0.02 Å. From the calculated coordinates of each atom in the supercell (including the oxygen atoms), we also calculate directly the time-dependent modulation in the structure factor, obtaining fractional modulations in the effective scattering intensity of 1% [Fig. 4(e)] for the applied fields used here, in excellent agreement with the experimental results. We note that this effect is in contrast to the ordinary decrease in scattering intensity that would be associated with a temperature-induced Debye-Waller effect [29,30]. Inclusion of the oxygen atoms in the above analytical calculation (see the Supplemental Material [26]) gives a slightly revised equation, which can be written as

$$\frac{\Delta I}{I_o} \sim \frac{36\pi^2 A_{\rm rms}^2(t)(f_{\rm Ba}f_{\rm Ti} + f_{\rm Ba}f_{\rm O} - 4f_{\rm Ti}f_{\rm O})}{(f_{\rm Ba} - f_{\rm Ti})^2 + f_{\rm O}^2 - 2f_{\rm Ba}f_{\rm O} + 2f_{\rm Ti}f_{\rm O}}.$$
 (4)

This changes the estimated magnitude of the induced rms displacement by  $\approx 10\%$ .

Based on the observed THz-field-induced out-of-plane rms displacement and the MD simulation, one can derive an atomistic understanding of the structural response of a ferroelectric upon ultrafast electric-field excitation, directly relating the induced out-of-plane motions to a field-induced transient polarization rotation of local dipoles following the applied in-plane THz field. Before application of the THz



FIG. 4. MD simulation results. (a) Schematic showing how a rotation of the polarization leads to an increase in out-of-plane rms displacements. (b) The angle of the net polarization with respect to the *c* axis. (c) The rms displacement of the Ti atom along the in-plane and out-of-plane direction after in-plane THz excitation. (d) Corresponding histograms showing distributions of in-plane and out-of-plane displacements before and at the peak of the THz field. The inset shows the MD simulation supercell from which these histograms are calculated. (e) Calculated structure factor modulation for the (003) reflection. (f) Projected net polarization along the *c* axis as a function of time.

field, BTO exhibits order-disorder character, with the Ti atoms distributed along the four (111) directions of the unit cells within the tetragonal phase [31-35], with this initial disorder likely underlying the lack of a coherent vibrational response. This is schematically shown in Fig. 4(a) (left), which depicts the distribution of dipoles within the ensemble of unit cells probed. Upon THz excitation, these dipoles rotate in the transverse electric field of the bias pulse such that the intrinsic in-plane distribution is transformed to one with an increased component along the out-of-plane direction, shown as the enhanced rms amplitude in Fig. 4(a) and in agreement with our observations. This simple model is supported by more detailed theoretical calculations: Fig. 4(b) shows calculations of the time-dependent induced rotation of the polarization in the applied THz field used in the experiments, showing rotation amplitudes of approximately 40°. This magnitude

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is consistent with simple estimates based on the known transverse susceptibility of BTO [36]. Figure 4(c) shows the time dependence of the rms displacements averaged over the simulated  $10 \times 10 \times 10$  supercell [shown in the inset to Fig. 4(d); see also the supplemental information [26]] comparing the in-plane to out-of-plane response. This shows, consistent with the simple model described above, that the in-plane rms distribution decreases, whereas the out-of-plane distribution increases. The magnitude of the simulated increase in the out-of-plane displacements is in good agreement with our experimental measurement. In addition, Fig. 4(d) shows histograms of the simulated displacements comparing before excitation (t = -1.5 ps) and at the peak of the THz field (t =2.2 ps), showing a response similar to that shown in Fig. 4(c). Finally, from the simulated spatial coordinates of the atoms within the supercell (Supplemental Material [26], Sec. 9), one may calculate directly the time dependence of the (003) reflection, showing a transient increase and then a decrease in Fig. 4(e), with good agreement comparing the magnitude of the change to the observed change in the diffracted intensity. Both simulated and calculated structure factor modulations rise with a time constant of a few picoseconds, although the simulated response turns off on about a  $3 \times$  faster time scale, more closely following the applied field. From the perspective of the polarization rotation model described above, this recovery time scale corresponds to the time for the polarization to reorient along its original direction, and this effect may depend in a more complicated way on the thin-film geometry, which is not accurately included in the simulations. Further experiments are required to investigate this effect. Although not directly measured here, the induced rotation leads to a decrease in the out-of-plane polarization of order 10% shown in Fig. 4(f), which can also be viewed from the perspective of a rotation of the ferroelectric polarization. This decrease corresponds to a displacement that is small compared to  $A_{\rm rms}$  justifying the assumptions made above. We emphasize that the experimentally observed ultrafast recovery on picosecond time scales shows that this time-dependent structure factor modulation and associated increase in rms displacements are not associated with field-induced temperature jumps, which will recover on much slower (nanosecond) time scales determined by thermal transport, as shown in Fig. 3. Complementary measurements on the (012) reflection (with an in-plane reciprocal-lattice vector component perpendicular to the applied in-plane THz field), described in the Supplemental Material [26], further confirm the above model.

As noted above, the transient structure factor modulations are superimposed on a large amplitude and long-lived homogeneous shift of the diffraction peaks to lower angles, corresponding to an increase in the *c*-axis tetragonality. This response can be understood as arising from the initial vibrational excitation of the thin film, with the peak frequency of the THz pulse resonant with the  $\sim$ 1 THz Slater E(TO) mode in BTO [37]. We note that a detailed model including the epitaxial clamping of the film to the substrate indicates that the Bragg peak shift is associated with a heating effect with magnitude  $\approx$ 70 K at the highest applied fields. In particular, this model accounts for the coupling between in-plane and out-of-plane stresses and the fact that the THz excitation only interacts to first order with the thin film and not the substrate. More details on this model are included in the Supplemental Material [26], Sec. 2. This observed transient increase in tetragonality is consistent with a simple Joule heating model: Using known conductivities at 1 THz (dominated by vibrational degrees of freedom), the energy absorbed by the thin film leads to an estimated maximum temperature change  $\Delta T \sim \frac{\sigma E^2 \Delta t}{C} = 20$  K for a peak field E = 0.7 MV/cm within the film, where the conductivity  $\sigma$  is calculated from the known optical constants at 1 THz frequency [37,38], C is the heat capacity, and  $\Delta t$  is the temporal width of the applied THz pulse. We estimate the peak field within the film using finite-difference time-domain simulations (shown in Fig. 1, with more details in the Supplemental Material [26]). This is also consistent with the effect size scaling quadratically with the THz electric field, as experimentally observed [Fig. 2(f)]. We note that the observed linear scaling with the intensity of the THz pulse is inconsistent with THz-driven ionization processes [39]. Further, this scaling and the observation of similar effects above the Curie temperature [Fig. 3(b)] rule out potential piezoelectric responses, while the long-lived nature of the response rules out both piezoelectric and electrostrictive stresses as playing important roles in the observed dynamics. A quantitative model for the THz-induced stress and strain together with a dynamical diffraction model [40-42] (see the Supplemental Material [26]) captures fully the observed onset time and magnitude of the long-lived effects and allows for quantitative fitting of the observed response, also shown in Fig. 2.

To conclude, femtosecond x-ray-diffraction measurements on THz-driven BTO directly capture the first atomic-scale steps in its electric-field-driven structural response. The combination of experimental observations with first-principles-based MD simulations shows evidence for large-amplitude rotations of the ferroelectric polarization occurring on ps time scales, as reflected in changes in the rms out-of-plane displacements of the central Ti atom within the unit cell. Additionally, these measurements capture the coupling between in-plane and out-of-plane vibrational modes and the concomitant high-

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frequency acoustic strains that can be driven by electric-field pulses. The results are in good agreement with a model in which the THz field is directly coupled to low-frequency modes of the BTO lattice and with first-principles-based MD simulations. Future studies probing additional x-ray reflections may enable direct reconstruction of the full unit-cell structural changes. In this transverse geometry, additional opportunities exist for visualization of dynamic electrocaloric responses and associated devices in which field-induced cooling or heating effects are directly resolved under both collinear  $(E \parallel P)$ and noncollinear  $(E \perp P)$  geometries. Novel possibilities with respect to terahertz-frequency photonic switches with unique photoelectromechanical responses also follow from this work.

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